PATENT COOPERATION TREAT

Translation



PCT

INTERNATIONAL PRELIMINARY REPORT ON PATENTABILITY (Chapter II of the Patent Cooperation Treaty)

(PCT Article 36 and Rule 70)

Applicant's or agent's file reference PCT083JST	FOR FURTHER ACTION	ON	See Form PCT/IPEA/416	
International application No. PCT/JP2003/007577 International filing date (day/month/year) 13 June 2003 (13.06.2003)			Priority date (day/month/year) 16 December 2002 (16.12.2002)	
International Patent Classification (IPC) or national classification and IPC H01L 29/06, 21/20, 21/203, 33/00, H01S 5/34, 5/50, H01L 21/205				
Applicant JAPAN	SCIENCE AND TEC	CHNOLOGY A	GENCY	
This report is the international prelir Authority under Article 35 and trans	ninary examination report, smitted to the applicant acco	established by this cording to Article 3	s International Preliminary Examining 6.	
 This REPORT consists of a total of This report is also accompanied by A 		cluding this cover	sheet.	
a. (sent to the applicant and	l to the International Burea		1	
and/or sheets con	itaining rectifications autho istructions).	orized by this Auth	peen amended and are the basis of this report cority (see Rule 70.16 and Section 607 of the	
beyond the discle	osure in the international agon.	application as med	ty considers contain an amendment that goes, as indicated in item 4 of Box No. I and the	
b. (sent to the International Bureau only) a total of (indicate type and number of electronic carrier(s)) , containing a sequence listing and/or tables related thereto, in computer readable form only, as indicated in the Supplemental Box Relating to Sequence Listing (see Section 802 of the Administrative Instructions).				
4. This report contains indications rel		s:		
Box No. I Basis of the	report	·		
Box No. II Priority Box No. III Non-establis	hment of opinion with rega	ard to novelty, inve	entive step and industrial applicability	
Box No. IV Lack of unity of invention				
Box No. V Reasoned str	Box No. V Reasoned statement under Article 35(2) with regard to novelty, inventive step or industrial applicability; citations and explanations supporting such statement			
Box No. VI Certain docu				
1	cts in the international applervations on the internations			
Date of submission of the demand 11 June 2004 (11.06)			04 February 2005 (04.02.2005)	
Name and mailing address of the IPEA/JI		Authorized office		
Raccimile NO		Telephone No.		



Inte	nal application No.
P	CT/JP2003/007577

Box No. I		s of the report	
otherw	ise indica	ne language, this report is based on the international application in ted under this item.	
	This rep which is	ort is based on translations from the original language into the follanguage of a translation furnished for the purpose of:	llowing language,
	inte	emational search (under Rules 12.3 and 23.1(b))	
	pul	lication of the international application (under Rule 12.4)	
	int	ernational preliminary examination (under Rules 55.2 and/or 55.3)	
furnisi and ar	hed to the re not an	the elements of the international application, this report is bath receiving Office in response to an invitation under Article 14 are sexed to this report): national application as originally filed/furnished	sed on (replacement sheets which have been referred to in this report as "originally filed"
\boxtimes	the descr		, as originally filed/furnished
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	a sentie	nce listing and/or any related table(s) – see Supplemental Box Rela	ting to Sequence Listing.
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		1. 1 in the correctletion of	
3.	The am	endments have resulted in the cancellation of:	
1	ti	ne description, pages	
	⊠ t	ne claims, Nos3, 10-11, 16-17, 21-22	· ·
1	□.	ne drawings, sheets/figs	<u> </u>
1		ne sequence listing (specify):	
1		ny table(s) related to sequence listing (specify):	
1	'لسا	in more(a) remise to a large and a large a	·
4.	made, (Rule	port has been established as if (some of) the amendments annexe since they have been considered to go beyond the disclosure as 70.2(c)). The description, pages	nied, as indicated in the Supplemental Box
* If it	tem 4 app	lies, some or all of those sheets may be marked "superseded."	



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Box No. IV La	ick of unity of invention
1. In res	ponse to the invitation to restrict or pay additional fees the applicant has:
ге	stricted the claims.
pa	aid additional fees.
pa	uid additional fees under protest.
ne	either restricted nor paid additional fees.
2. This Au not to in	othority found that the requirement of unity of invention is not complied with and chose, according to Rule 68.1, nivite the applicant to restrict or pay additional fees.
3. This Authority	y considers that the requirement of unity of invention in accordance with Rules 13.1, 13.2 and 13.3 is
complie	d with.
not com	plied with for the following reasons:
See s	upplemental sheet
	·
4. Consequently	, this report has been established in respect of the following parts of the international application:
⊠ al	ll parts.
tt	ne parts relating to claims Nos.

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Supplemental Box (To be used when the space in any of the preceding boxes is not sufficient)

Continuation of: IV. 3.

The invention described in claims 1, 2, and 4 to 7 pertains to a semiconductor laminate structure having non-uniform quantum dots; the invention described in claims 8, 9, and 12 to 14 pertains to a light-emitting diode using a semiconductor laminate structure having non-uniform quantum dots; the invention described in claim 15 and claims 18 and 19 pertains to a semiconductor laser diode using a semiconductor laminate structure having non-uniform quantum dots; and the invention described in claim 20 and claims 23 and 24 pertains to a semiconductor optical amplifier using a semiconductor laminate structure having non-uniform quantum dots.

The invention described in claims 25 to 29 pertains to a manufacturing method for a semiconductor device using a semiconductor structure having non-uniform quantum dots, but claims 25 to 29 cannot be said to describe a single method applied particularly in order to manufacture the semiconductor laminate structure having non-uniform quantum dots of the invention described in claims 1, 2, and 4 to 7.

(The manufacturing method of the invention described in claims 25 to 29 cannot be considered a method of manufacturing quantum dots which are characterized in that "the different quantum dots are formed from non-uniform quantum dots having both/either different sizes and/or compositions and comprising a compound semiconductor," and that "the non-uniform quantum dots have a plurality of quantum levels corresponding to a plurality of wavelengths which include at least either of ultraviolet light to visible light or infrared light including the 1.3 μm band and the 1.5 μm

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Supplemental Box			
(To be used when the space in	any of the pre-	ceding boxes is:	not sufficient)

Continuation of: IV. 3.

band, and which with the input of electrical current, serve as the emission peak(s).")

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V.	Reasoned statement under Article 35(2) with regard to novelty, inventive step or industrial applicability;
••	citations and explanations supporting such statement

Statement			*****
Novelty (N)	Claims	1, 2, 4-9, 12-15, 18-20, 23-30	YES
Tioners (19)	Claims		NO
	Ol-i		YES
Inventive step (IS)	Claims	1, 2, 4-9, 12-15, 18-20, 23-30	NO
Industrial applicability (IA)	Claims	1, 2, 4-9, 12-15, 18-20, 23-30	YES
	Claims		NO
	Statement Novelty (N) Inventive step (IS) Industrial applicability (IA)	Novelty (N) Claims Inventive step (IS) Claims Claims Claims Claims Claims	Novelty (N) Claims Inventive step (IS) Claims Claims 1, 2, 4-9, 12-15, 18-20, 23-30 Industrial applicability (IA) Claims 1, 2, 4-9, 12-15, 18-20, 23-30 Industrial applicability (IA)

Citations and explanations

- Document 1: Y. Nonogaki et al., "Formation of InGaAs dots on InP substrate with lattice-matching growth condition by droplet heteroepitaxy,"

 Compound Semiconductors 1998 Institute of Physics Conference Series, No. 162, 1999, pages 469-473
- Document 2: JP 2002-43696 A (Fujitsu Ltd.), 8 February 2002, paragraphs [0028]-[0035], [0100][0114], fig. 7 (Family: none)
- Document 3: JP 9-326506 A (Fujitsu Ltd.), 16 December 1997, paragraphs [0040]-[0051], fig. 15-17 (Family: none)
- Document 4: US 2001-028755 Al (Fujitsu Ltd.), 11 October 2001, paragraphs [0061]-[0082], paragraph [0109], fig. 6, 9, 10, & JP 2001-255500 A
- Document 5: JP 2000-196065 A (Fujitsu Ltd.), 14 July 2000, paragraphs [0026]-[0030], [0056]-[0060], fig. 3, 8, 9 (Family: none)

Claims 1 to 30

Document 1 does not disclose a compound semiconductor characterized in that quantum dots have mutually differing compositions.

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However, the double heterostructure wherein cladding layers having a bandgap greater than that of an active layer are provided on both sides of said active layer is a known quantum structure disclosed in documents 2 to 4, and moreover, the active layer and cladding layers of the semiconductor devices disclosed in documents 2 to 4 comprise compound semiconductors having constituent elements such as Ga or the like, which serve as a source of "meltback and mutual dispersion of the constituent elements of the compound semiconductor."

Accordingly, a person skilled in the art could easily conceive of applying the aforementioned double heterostructure to the quantum dots disclosed in document 1, thereby deriving an invention wherein there is "meltback and mutual dispersion of the constituent elements of the compound semiconductor."

VIII. Certain observations on the international application

The following observations on the clarity of the claims, description, and drawings or on the question whether the claims are fully supported by the description, are made:

(1) The meaning of the phrase "have a plurality of quantum levels," used in the statement of claim 1, wherein "the non-uniform quantum dots have a plurality of quantum levels corresponding to a plurality of wavelengths which include at least either of ultraviolet light to visible light or infrared light including the 1.3 μ m band and the 1.5 μ m band, and which with the input of electrical current, serve as the emission peak(s)," is unclear.

(It is unclear whether each individual quantum dot "has a plurality of quantum levels," or whether, in order that the quantum level of individual quantum dots be different, there exists a plurality of quantum levels for entire groups of multiple non-uniform quantum dots.)

- (2) For the same reason, the meaning of the phrases "have a plurality of quantum levels" and "having a plurality of quantum levels" used in claims 2, 8, 9, 15, and 20 is unclear, and thus, it is not clear what the inventions described in claims 2 to 24 are.
- (3) The description of the present application states that:

"[A]n Al_{0.26}Ga_{0.21}In_{0.53}As layer (3b) is laminated onto the quantum dots (19) in a thickness of, for example, 5 to 10 nm. While this layer is being grown, meltback and mutual dispersion of the n-type cladding layer (5) and ... the constituent elements of the compound semiconductor serve to give the quantum dots (19) a composition that is not simply InAs, but

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7 6 11 1 2 2 2 2 2 2 2 2 2 2 2 2 2 2 2 2	rational application				
II. Certain observations on the inte			ot dloom	what the	
claim 25 is unc				wiiat tile	
inventions descr	ribed in claims	3 25 to 3	30 are.		
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